

Ternary Nb₃Sn superconductors with artificial pinning centers and high upper critical fields

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Abstract

In this letter we demonstrate the development of ternary Nb₃Sn multifilamentary conductors with artificial pinning centers (APC) which achieve high critical fields. These recently-developed conductors were tested in a 31 T magnet, and the results showed that their upper critical field (B_{c2}) values at 4.2 K are 27-28 T, and irreversible field (B_{irr}) values are above 26 T, values similar to or higher than those of best RRP conductors. The non-Cu J_c has been brought to nearly 1200 A/mm² at 16 T and 4.2 K, comparable to RRP, in spite of the fact that the fine-grain Nb₃Sn fractions in filaments are still low (20-30%) and the grain sizes are still not fully refined (70-80 nm) due to conductor designs and heat treatments that are not yet optimized. The Nb₃Sn layer J_c at 4.2 K, 16 T is 4710 A/mm² for the APC wire with 1%Zr, about 2.5 times higher than RRP conductors, in spite of the fact that its grain size is not yet fully refined due to insufficient oxygen and unoptimized heat treatment. An analysis is presented about the non-Cu J_c that can be achieved by further optimizing the APC conductors and their heat treatments.

Keywords: Nb₃Sn Superconductor, Artificial pinning center, B_{c2} , J_c .

1. Introduction

Several next-generation proton-proton circular colliders have been proposed to succeed the Large Hadron Collider (LHC), including the Future Circular Collider (FCC) and the High-energy LHC (HE-LHC), for both of which 16 T magnets based on Nb₃Sn superconductors are being studied as the baseline for the main dipoles [1]. Specifications for Nb₃Sn conductors, including a non-Cu J_c of 1500 A/mm² at 4.2 K and 16 T (corresponding to ~1950 A/mm² at 4.2 K and 15 T), have been selected and are being used for the magnet designs [2]. Magnets built with conductors of lower J_c would require larger coils, which would lead to a large increase in cost. The J_c of the state-of-the-art Nb₃Sn conductors, which are the rod-restack-process (RRP) type, is not as high as we need: even the record J_c reached by the top-performing RRP conductors is 10-15% below the above target [3,4]; moreover, the ~30% spread of J_c among RRP billets which is seen in wires with subelement size (D_s) of 55 μ m [3,4] means that in fact a ~45-50% improvement in J_c is required to reach the needs of FCC. After substantial optimization in the past two decades, RRP wires have become excellent technical conductors, and significant achievements have been made in reducing D_s [5], but the J_c performance has been at a plateau since the early 2000s [6]. Extensive efforts have been made to improve the J_c level, including fine tuning of precursors such as local area ratios (LAR), doping, and heat treatments; however, these have not led to any substantial change to the stagnant performance levels.

It is shown in [4] that there are three factors determining the non-Cu J_c of a uniform Nb₃Sn conductor: fine-grain (FG) Nb₃Sn fraction within subelements, irreversibility field (B_{irr}), and fluxon pinning capacity; of the three, the greatest potential for further improving non-Cu J_c lies in enhancing fluxon pinning [4]. For example, proton or neutron irradiation on reacted Nb₃Sn conductors [7,8] demonstrated significantly improved non-Cu J_c s by introducing point pinning

centers (e.g., to the record-breaking 2270 A/mm^2 at 4.2 K and 15 T [7]), although using irradiation processing for wind-and-react Nb_3Sn magnets is difficult. In fact, introducing additional pinning centers (APC) to Nb_3Sn conductors has long been a “holy grail” in the Nb_3Sn community, with various efforts on a number of techniques since the 1980s, but none succeeded in making high- J_c wires [9-13]. The internal oxidation (IO) technique, which adds Zr and O to Nb for forming ZrO_2 particles that refine Nb_3Sn grains, is a promising approach given its big success in the 1960s in Nb_3Sn tapes reacted above $950 \text{ }^\circ\text{C}$ [14]; nevertheless, transferring the technique to wires was challenging. Attempts to apply it in Nb_3Sn wires reacted below $800 \text{ }^\circ\text{C}$ by Zeitlin with various ingenious methods did not show grain refinement [12]. Nearly 10 years later, in a review of the literature, we worked out the essentials for applying the IO technique in Nb_3Sn wires [15], and then successfully realized it: we achieved first on binary monofilament wires [15,16] a refinement of average grain sizes from 120-150 nm down to 35-50 nm, as well as a doubling of Nb_3Sn layer J_c at 12 T despite its low B_{irr} (20 T) that is mostly due to lack of Ta/Ti dopant. It also showed shift of pinning force versus field (F_p - B) curve peaks to higher field (from $0.2B_{irr}$ to $0.33B_{irr}$), which enhanced high-field J_c and suppressed low-field J_c [16]. With this, engineering fluxon pinning of Nb_3Sn wires finally became a reality, leading to great promise to push their performance to much higher levels.

Also in [16] we proposed applying this technique in the simple powder-in-tube (PIT) design where oxide powder is blended into Sn source powders as filament cores. Its feasibility was reinforced by the observation in early 2015 of oxygen transfer from oxide to Nb without direct contact (i.e., via vapor) [17,18]. Then SupraMagentics Inc. fabricated some binary PIT-APC wires with 120 filaments, which were characterized at Florida State University (FSU) and Brookhaven National Lab (BNL) [19], as well as Ohio State University (OSU) [20]: both effects

of refined grain size (<40 nm) and shift in F_p - B curve peak were clearly verified [19,20]. Hyper Tech Research Inc. (HTR) fabricated some 61-filament binary PIT-APC wires, which were drawn to D_s of 24 μm [18]. However, both SupraMagnetics and HTR's early binary PIT-APC wires had low B_{irr} and needed improvement in wire quality and recipe.

Development of ternary PIT-APC multifilamentary wires began in earnest from 2017, as a collaboration between Fermilab, HTR, and OSU, with focus on improving conductor design, including filament architecture, precursor selection, precursor ratios, tube size, and powder packing density, etc. These efforts have led to significant improvement of performance of the APC conductors in the past two years, while this improvement process is still ongoing. Meanwhile, these progresses also aroused great interest in Nb_3Sn pinning work in other groups recently. In parallel there is also some interesting work on APC Nb_3Sn with new alloys at FSU [21]. Also, exciting results have been obtained on APC Nb_3Sn at University of Geneva based on the IO method [22]. In this letter we demonstrate that ternary PIT-APC Nb_3Sn conductors with high B_{c2} and B_{irr} have been achieved, with competitive transport J_c , and also discuss the potential for further J_c improvement.

2. Experimental

2.1. Samples

The PIT-APC multifilamentary wires used for this work were fabricated by HTR. So far all of the APC wires have been made using a 48/61 design (i.e., 48 Nb_3Sn filaments and 13 Cu hexagonal rods) with a Cu/non-Cu ratio of ~ 1.3 . Designs with higher filament counts are in the preparation stage. All wires were fabricated with a starting billet diameter of 19 mm and drawn

to various final wire diameters of 0.5-1.0 mm, resulting in a total length of 100-200 meters for each billet depending on final diameters. After continuous optimization of conductor recipe and improvement of the fabrication process, presently all APC wires can be routinely drawn to the final sizes in single pieces: none of the past 15 billets had any wire breakage.

Two of our most recent multifilamentary APC conductors have been tested at the National High Magnetic Field Laboratory (NHMFL) and the results are reported here. Conductor A (T3851, denoted as APC-A) used Nb-0.6%Zr-3at.%Ta tube, in which both Zr and Ta contents fell short of target due to problems in making that batch of alloy, while Conductor B (T3882, denoted as APC-B) used Nb-1%Zr-4at.%Ta tube. Both conductors used mixture of Sn, Cu, and SnO₂ powders. APC-A had enough oxygen for each filament, but the recipe was not yet fully optimized for Cu/Sn and Nb/Sn ratios, as will be discussed below. On the other hand, it was found that APC-B had an insufficient level of oxide due to unoptimized recipe and precursor selection: as a result, some filaments were only partially oxidized.

In order to compare results of the APC wires and present Nb₃Sn conductors, two reference wires were also measured. One is a standard Ti-doped RRP wire for quadrupole magnets in the High Luminosity LHC (HL-LHC) upgrade, which has a diameter of 0.85 mm and 108/127 subelements; other parameters specified in [3]. The other is a standard commercial Ta-doped tube type (TT) wire made by HTR, T1505, with a diameter of 0.7 mm and 192/217 filaments; other parameters described in [23]. The two wires are denoted as “RRP” and “TT”, respectively.

All wires were heat treated either in straight segments or on standard ITER barrels under vacuum or, alternatively, in argon-flowing furnaces. APC-A (0.7 mm diameter) was reacted at 675 °C for 152 hours, and APC-B (0.84 mm diameter) was reacted at 675 °C for 300 hours, both with a standard ramp rate of 30 °C/h without any intermediate steps. The RRP wire was heat

treated using the standard protocol: 210°C/48h + 400°C/48h + 665°C/75h [3]. The TT wire was heat treated at 625 °C for 400 hours. It is known from various earlier studies [4,24,25] that B_{irr} s of PIT and TT conductors are not sensitive to reaction temperature in the 625-675 °C range.

2.2. Measurements

Two different types of tests were performed at NHMFL. The first was a measurement of resistance vs field (R - B), and was used to determine B_{irr} and B_{c2} as in [26]. The second was voltage vs current (V - I) taken at a given B . All measurements used a four-point method and were performed at 4.2 K in a 31 T DC magnet at NHMFL with fields perpendicular to wire axes. For each measurement, great care was taken to ensure the samples were centered within the magnet. For the R - B measurements, the sample length was 15 mm and the voltage tap separation was 5 mm; a sensing current of 31.6 mA was used. Because 5 samples could be mounted together for each run, we always included at least one reference wire which gave a second check on the results. The voltages were recorded both for increasing and decreasing magnetic fields; hysteresis was minimized by the choice of time constant and was embedded in our error estimates for the critical field determinations (~ 0.2 T). For V - I tests on straight samples, each segment of 35 mm was measured with voltage tap separation of 5 mm, and a criterion of 1 μ V/cm was used to determine the critical current (I_c). For ITER barrels the voltage tap separation was 50 cm and a criterion of 0.1 μ V/cm was used to determine I_c .

3. Results and Discussions

The R - B curves of APC-A and APC-B are shown in Fig. 1, along with RRP and TT. Also included is an APC wire fabricated in 2017 (denoted as “APC17”) which used the same Nb-

0.6%Zr-3at.%Ta tube as APC-A but had much lower wire quality (e.g., with bad filaments). APC17 at 0.7 mm was reacted at 675 °C for 150 hours. The fields at 10%, 50%, and 90% of the R - B transitions are shown in Table 1. Below we take 10% as B_{irr} and 90% as B_{c2} .

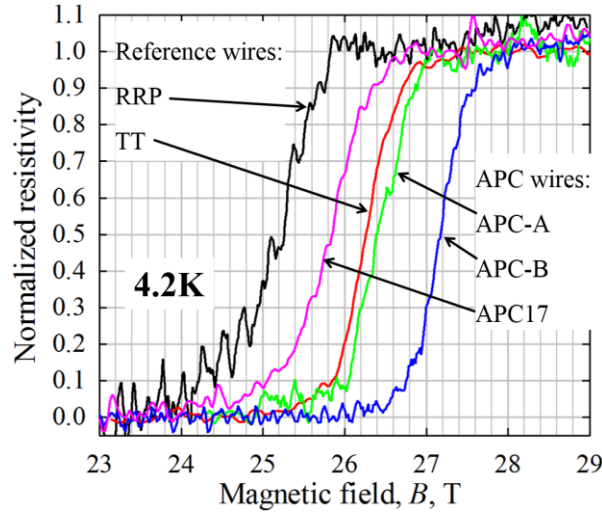


Figure 1. The R - B curves of the two reference and three APC wires.

Table 1. B_{c2} (4.2 K) values as determined from the R - B curves

	RRP	TT	APC-A	APC-B	APC17
B_{c2} -10%	-*	25.9	26.0	26.8	25
B_{c2} -50%	25.2	26.3	26.4	27.2	25.8
B_{c2} -90%	25.8	26.7	26.9	27.6	26.3

*: The accurate B_{c2} of RRP at 10% of transition is difficult to define due to noise in the curve.

The B_{c2} of the RRP wire is 25.8 T, which is in the typical range for RRP conductors reacted at 665 °C. The TT wire has B_{c2} of 26.7 T, ~1 T higher than the RRP wire. Higher B_{c2} s observed in TT and non-APC PIT conductors as compared to RRP given heat treatments optimal for best J_c performance have been reported by numerous studies [4,24,25]. This is most likely due to better stoichiometry in TT and PIT conductors, in which the Sn source is mostly Nb_6Sn_5 and

high-Sn Cu-Sn which have high chemical potentials of Sn. A recently-developed theory for stoichiometry of Nb₃Sn conductors explains this effect [4,27]. The B_{c2} of APC-A is 26.9 T, ~0.2 T higher than TT. As mentioned earlier, APC-A wire has insufficient Ta content (3 at.%); its B_{c2} could be higher if the Ta content was increased to the optimal level (4 at.%). The APC-B had a B_{c2} of 27.6 T, ~2 T higher than RRP.

The above results clearly show that the IO technique slightly enhances B_{c2} of Nb₃Sn instead of reducing it. This is quite different from NbTi conductors, in which a clear suppression of B_{c2} was seen when APCs were incorporated [28]. The reason is that in NbTi conductors APCs were typically normal conducting metals, which suppress superconductivity due to the proximity effect [28]. On the other hand, the IO technique forms ZrO₂ particles in Nb₃Sn; because ZrO₂ is a ceramic and insulator, it has no effect on the superconductivity of Nb₃Sn. The low B_{irr} s obtained on previous monofilaments [16] and multifilamentary wires [18,19] could be due to lack of Ta or Ti dopant and poor wire quality. Indeed, wire quality has a significant influence on B_{c2} : for example, APC17 has noticeably lower B_{c2} than APC-A and even TT. The APC-A and APC-B wires are better in quality and thus exhibit higher B_{c2} s.

The non-Cu J_{cS} calculated from the I_{cS} of APC-A and APC-B are shown in Fig. 2, along with the reference RRP wire. The data points are fitted with the commonly-used two-component pinning force model [11], which has been proven by several studies to work well for APC conductors [7,11,19]. As can be seen from Fig. 2, the fittings to the data points are very good. The obtained B_{irr} parameters from the fittings are 24.6 T, 25.2 T, and 26.2 T for RRP, APC-A, and APC-B, respectively. These values agree well with the fields where transitions of the $R-B$ curves start, further confirming the B_{irr} results. The non-Cu J_{cS} of RRP are ~1090 and ~2680 A/mm² at 16 T and 12 T, respectively, which are not the highest values reached by the top-

performing RRP conductors, but still in the typical J_c spectrum for a RRP wire with D_s of 55 μm . The non-Cu J_c s at 16 T of APC-A and APC-B are 1150 and 1040 A/mm^2 , respectively. Both APC wires had clear advantage in high-field J_c s relative to RRP due to higher B_{irr} s and shift in F_p - B curve peaks.

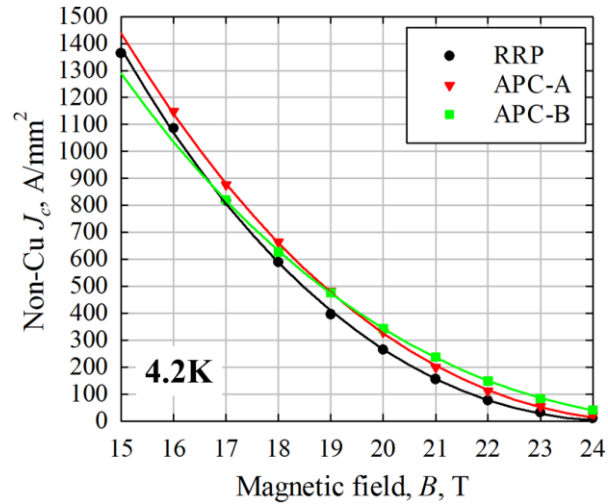


Figure 2. Non-Cu J_c s (4.2 K) of RRP, APC-A, APC-B.

Back-scattered electron (BSE) images of polished cross sections of the two APC wires are shown in Fig. 3. From the images it can be calculated that the average FG area fractions in filaments are $\sim 33\%$ and $\sim 22\%$ for APC-A and APC-B, respectively, and the residual Nb area fractions are 36% and 45%, respectively. The calculated coarse-grain (CG) fractions for APC-A and APC-B are $\sim 13\%$, similar to those of TT [25] and PIT [29] wires. In comparison, the residual Nb fractions for present PIT conductors are typically below 25% [29]. This means that the above APC conductors can form more FG by converting more Nb via properly tweaking the recipe design (e.g., Nb/Sn ratio) and optimizing reaction so that no Sn remains in the core. Our

calculation shows that by doing the above and reducing the barrier fraction to 25%, the FG fraction would reach 40% or slightly above, as in TT and PIT conductors [25,29].

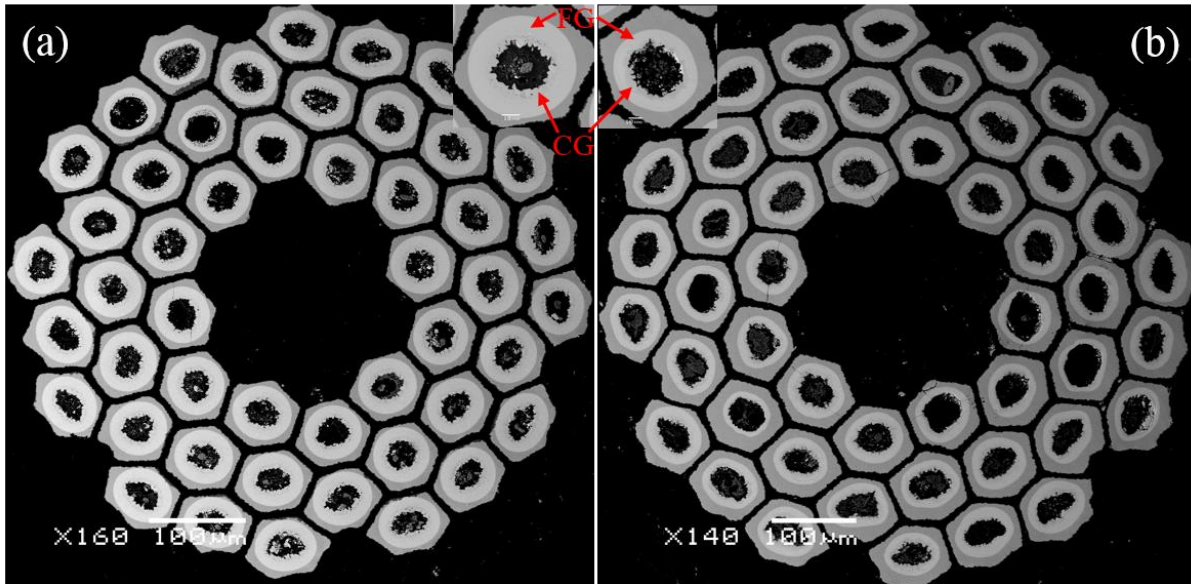


Figure 3. BSE images of cross sections for reacted (a) APC-A and (b) APC-B.

Also seen from Fig. 3 is that there is still some variation of Nb_3Sn fraction among filaments, which is also seen along the wire length. This apparently suppresses the overall I_c because the maximum current carried by a filament is determined by its worst segment. Such a non-uniformity issue may be caused by inhomogeneous powder distribution or perhaps some local Sn leakage into the Cu matrix before filaments are fully reacted. The former issue can be solved by improving powder mixing and filling techniques. For the latter case, the most common issue is local thinning of Nb alloy tube (e.g., filament cores being off the centers). This issue has been largely solved by development work in the past two years via proper attention to powder precursors as well as their ratios and mixing. Further improvements are being pursued.

From the above measured non-Cu J_{cs} and FG area fractions, the Nb₃Sn layer J_{cs} are calculated and shown in Fig. 4. The 16 T layer J_{cs} for RRP, APC-A, APC-B are 1850, 3450 and 4710 A/mm², respectively, while that of the top-performing RRP wires is ~2200 A/mm². Clearly the APC wires have higher advantage at higher fields.

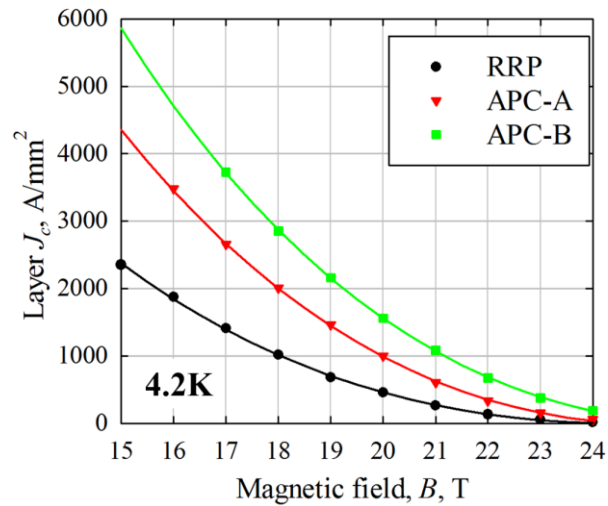


Figure 4. Nb₃Sn layer J_{cs} (4.2 K) of RRP, APC-A, APC-B.

Secondary-electron (SE) images of fractured cross sections of the two APC samples are shown in Fig. 5. It was found that grain size distributions in the FG layers are not uniform. The calculated average grain sizes of APC-A and APC-B after 675°C reactions were 81 and 72 nm, respectively, which are about half of those RRP and PIT wires reacted at 650-675 °C [4,30], but much larger than the average grain sizes of the early APC samples with 1% Zr and sufficient O reacted below 650 °C, which were 35-45 nm [15,19,20]. For APC-A, this is because it was reacted at 675 °C and it had only 0.6%Zr in the Nb alloy: lower Zr content leads to fewer ZrO₂ particles for grain refinement. For APC-B, the less refined grain size is because it was reacted at

675 °C and it did not have sufficient oxygen due to an unoptimized recipe. Earlier studies indicate that grain size is sensitive to oxygen content, and that by optimizing the conductor recipe to fully oxidize all filaments, the average grain size can be reduced to 50-65 nm for reactions at 650-675 °C [15,18]. With B_{irr} above 25 T, grain sizes of 50-65 nm are expected to lead to a Nb₃Sn layer J_c at 16 T of 5000-6000 A/mm², as a conservative estimation based on the relation between J_c and grain size [16,30].

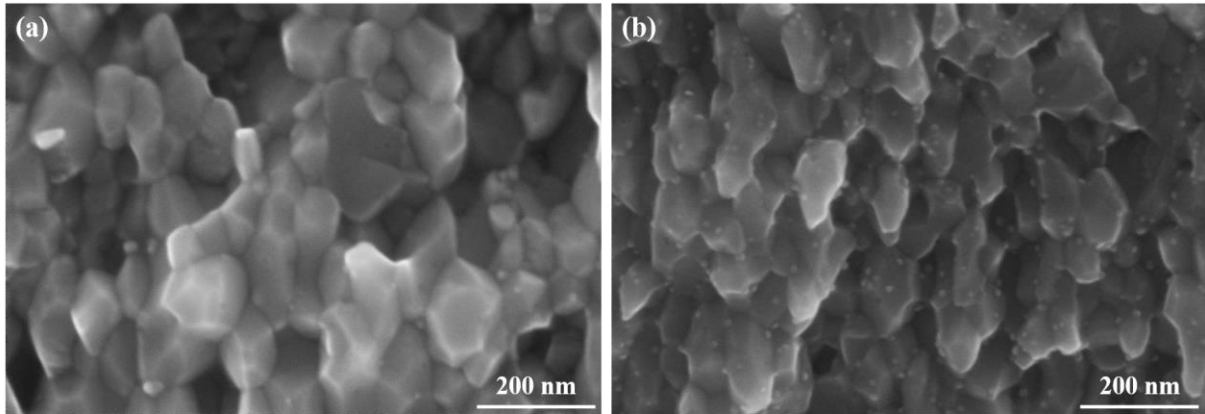


Figure 5. SE images of fractured cross sections of (a) APC-A (average grain size 81 nm) and (b) APC-B (average grain size 72 nm).

4. Conclusions

Although the APC technique was first realized in Nb₃Sn wires in 2014, focused development of ternary multi-filamentary PIT-APC wires began only in 2017, and since then progress has been fast. Measurements at NHMFL of the recently-developed ternary APC conductors gave B_{irrS} and B_{c2S} in the 26-28 T range, values that are at or above those of the best RRP conductors. The non-Cu J_{cs} of these APC conductors have reached nearly 1200 A/mm² at 16 T and 4.2 K,

similar to present RRP conductors, in spite of the fact that the FG fractions are still significantly below those of present-day PIT, TT, and RRP conductors due to the lack of recipe and heat treatment optimizations. The measured Nb_3Sn layer J_c of the APC wire with 1%Zr reacted at 675 °C is 4710 A/mm² at 16 T and 4.2 K, while that of RRP is below 2000 A/mm². The reason for the large increase in layer J_c for the APC conductor is mainly enhanced fluxon pinning, due to refined grain size and also ZrO_2 APCs in Nb_3Sn grains. The APC wire with 1%Zr had average grain size of ~72 nm, about half of those of RRP conductors, but can still be further reduced via recipe and heat treatment optimizations. We are presently working to optimize the conductor recipe and heat treatment in order to fully react the filaments (targeting 40% FG), as well as reduce the grain size to the previously observed 50-65 nm by fully oxidizing all of the filaments. If the targeted FG fraction and layer J_c can be reached, the non-Cu J_c at 16 T and 4.2 K should scale to 2000 A/mm² or above, greater than the target for FCC so that sufficient margin can be provided, representing a crucial advance for Nb_3Sn conductors.

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